



31VPP OUTPUT PIEZO SOUNDER DRIVER WITH BOOST CONVERTER

### Description

The PAM8907 is a piezoelectric horn driver with built-in boost converter, capable of driving a ceramic/piezo sounder with up to 31VPP output. With integrated boost converter, the PAM8907 can provide an optimized solution with higher Sound Pressure Level (SPL) for louder output sound, lower quiescent current for longer standby time, and auto turn-on/off feature for extended operating lifetime. The PAM8907 provides clear benefits for battery-operated tracker, piezoelectric horn or alarm related applications.

The PAM8907 integrates a boost converter that operates at a typical frequency of 1.8MHz. With integrated boost converter and unique piezo sounder driver technology, the PAM8907 provides small inrush current, low EMI and yet highly efficient system performance. PAM8907 boost converter output can be set to either 11V or 15.6V with minimum external components for various application usages.

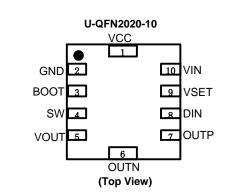
The PAM8907 has built-in automatic shutdown and wake-up functions for longer operating lifetime requirement. It also features thermal shutdown protection, overcurrent protection, overvoltage protection and undervoltage lockout protection to assure safe system operation.

The PAM8907 is available in U-QFN2020-10 package.

### **Features**

- Supply Voltage Range from 1.8V to 5.5V
- Intergraded Boost Converter VOUT = 11V or 15.6V
- Drive Piezo Sounder with up to 31VPP
- High-Speed Driver Designed with Very Short Turn-On/Turn-Off
- No Voltage Cross Output at Shutdown Mode
- High Impendence Output at Shutdown Mode
- Low Current Consumption, with Shutdown Current < 1µA</li>
- Automatic Shutdown and Wake-Up Control
- Available in Space-Saving U-QFN2020-10 package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

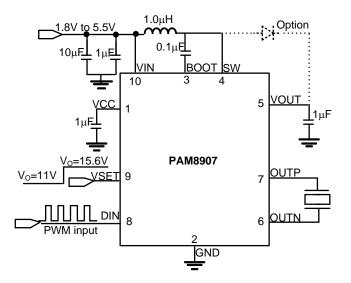
## **Pin Assignments**



## Applications

- Bluetooth or wireless location trackers
- Air humidifier or ultrasonic related piezo driver applications
- Security devices, home appliances
- Haptic feedbacks

## **Typical Applications Circuit**



Note: Schottky diode is optional. If added, it can save 20% of power consumption.

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

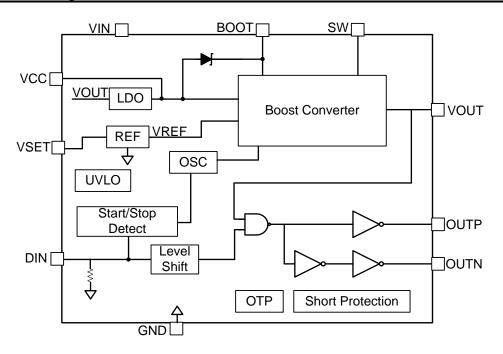
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Pin Descriptions**

Pin Number	Pin Name	I/O/P	Function
1	VCC	0	LDO Output
2	GND	Р	Ground
3	BOOT	0	Bootstrap Cap Connection
4	SW	I/O	Switch Pin Connect with External Inductor Pin
5	VOUT	0	Boost Output
6	OUTN	0	Negative Output
7	OUTP	0	Positive Output
8	DIN	I	PWM Signal Input, then End Signal Should be "L" to Disable the Chip
9	VSET	I	TTL Low Vout = 11V, TTL High Vout = 15.6V
10	VIN	I	Battery Voltage Input
_	Epoxy Pad	Р	Connect to GND

## **Functional Block Diagram**





## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristics	Value	Unit
VIN	Supply Voltage	-0.3 to 6.0	V
V <sub>IH</sub>	High-Level Input Voltage	-0.3 to 6.0	V
V <sub>IL</sub>	Low-Level Input Voltage	-0.3 to 6.0	V
TA	Operating Free-Air Temperature Range	-40 to +125	۵°
TJ	Operating Junction Temperature Range	-40 to +150	°C
Tstg	Storage Temperature Range	-65 to +150	°C

## **Recommended Operating Conditions** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristics		Min	Max	Unit
VIN	Supply Voltage	—	1.8	5.5	V
V <sub>IH</sub>	High-Level Input Voltage	DIN	1.2 to V <sub>IN</sub> + 0.3		V
V <sub>IL</sub>	Low-Level Input Voltage	DIN	-0.3	0.4	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+85	°C

## **Thermal Information**

Parameter	Symbol	Package	Maximum	Unit
Thermal Resistance (Junction to Ambient)	θја	U-QFN2020-10	68	°C/W
Thermal Resistance (Junction to Case)	θις	U-QFN2020-10	25	°C/W

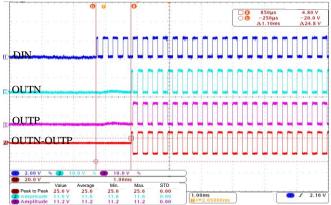
## Electrical Characteristics (@T<sub>A</sub> = +25°C, V<sub>IN</sub> = 3.0V, C<sub>PIEZO</sub> = 33nF, f<sub>DIN</sub> = 3.2kHz, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	Vin	—	1.8		5.5	V
Output Voltage Range	Vour	V <sub>OUT</sub> Boost Output Voltage (VSET Pin L/H)	_	11	_	V
Output Voltage Kange	V001			15.6		v
Shutdown Current	Isd	V <sub>DIN</sub> = 0V	0	0.03	1	μA
Oscillating Frequency	fosc	Boost Frequency	—	1.8	—	MHz
Static Drain to Source		High Side, I = 100mA	—	7.5	_	Ω
On-State Resistor	RDS(ON)	Low Side, I = 100mA		3	_	Ω
VOUT Start Delay Time	ton	From DIN Signal High to 90% V <sub>OUT</sub> Steady State	_	1.1	_	ms
Shutdown Delay Time	toff	From DIN = $H$ - > L, V <sub>OUT</sub> to GND	—	104	—	ms
Output Short-Circuit Current	lsc	OUTP and OUTN short	_	14	_	mA
Control Terminal Voltage H	Vih	DIN Pin	1.5		Vin	V
Control Terminal Voltage L	VIL	DIN Pin	0		0.4	V
Control Terminal Current H	Ін	DIN = V <sub>IN</sub>	_	2	10	μA
Control Terminal Current L	lı∟	DIN = 0	_	0.01	1	μA
Over Temperature Threshold	OTP	—	—	+150		°C
Over Temperature Protection Hysteresis	_	_	_	+30	_	°C

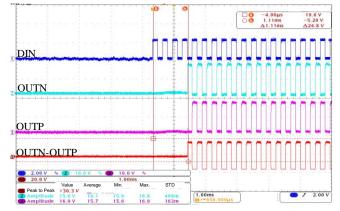


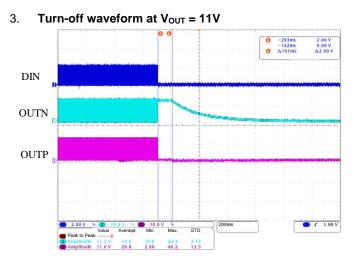
## Performance Characteristics (VDD = 3V, fDIN = 3.2kHz, VSET = L/H, CLOAD = 15nF/33nF, unless otherwise specified.)



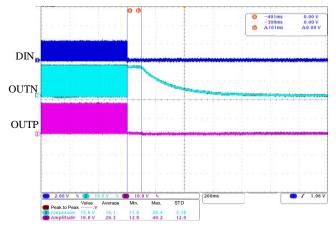


2. Turn-on waveform at V<sub>OUT</sub> = 15.6V





4. Turn-off waveform at V<sub>OUT</sub> = 15.6V





## **Application Information**

#### **Overview:**

The PAM8907 is a piezo sounder driver with integrated boost switch, power diodes, and fully differential amplifier. This versatile device is capable of driving piezo sounder for a variety of applications, including location tracker, air humidifier or haptic feedback related applications. The PAM8907 supports selectable boost voltage output by VSET pin for low/high-voltage output. A typical start-up time of 1.1ms makes the PAM8907 an ideal piezo driver with fast response. PAM8907 has built-in thermal overload protection, current limit and various protection features to prevent the device from damage when overdriven.

Major functions of PAM8907 along with application information is described in the following sections.

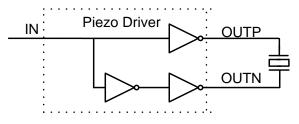
#### LDO Regulator

The PAM8907 has a built-in 5V LDO regulator to supply 5V to the internal blocks. It is recommended to add 1µF capacitor at pin 1 VCC (LDO).



#### **Piezo Driver**

As illustrated below, the PAM8907 has a built-in Piezo driver circuitry with Diodes Incorporated's proprietary design. This is to enable easy system configuration for driving piezo sounder with less external components and yet optimized performance.



#### **DIN Control**

The PAM8907 designs a binary control logic circuit internally for the automatic shutdown and wake-up control, when DIN is set low and continue for longer than 100ms (Typ.) period, PAM8907's boost and Piezo driver block will be disabled and the device automatically enters shutdown mode. The PAM8907's operation current is less than 1µA under this shutdown mode. When DIN is set high or provided with pulsed-clock input, PAM8907's boost and Piezo driver block to normal operation mode.



### Application Information (continued)

#### **Boost Regulator**

The PAM8907 boost regulator is a conventional current-mode controller with the following enhanced features:

- Undervoltage Lockout (ULVO): When the input supply (VIN) drops below the UVLO value, the boost regulator will switch off. Typical UVLO value is 1.6V.
- Over Temperature Protection (OTP): When PAM8907 die temperature is higher than OTP threshold, the boost regulator will switch off, and restart after OTP condition is removed. Typical OTP value is set at +160°C.
- VOUT Undervoltage (UV) Protection: When the boost regulator output voltage is lower than the preset threshold, it will trigger VOUT UV protection, and the device will go to hiccup mode in order to reduce power-supply current.
- VOUT Overvoltage (OV) Protection: When the boost regulator output voltage is higher than the preset threshold, it will trigger VOUT OV protection, and the device will switch off until VOUT OV condition is removed.
- Soft-Start: The boost regulator voltage setting is designed to always operate under soft-start operation, which can reduce inrush current. Typical soft-start time is set around 1.1ms.
- Overcurrent Protection (OCP): The boost regulator has a built-in cycle-by-cycle overcurrent protection.
- SLEEP: The boost regulator will go to sleep mode under light-load condition.

The PAM8907 has designed the boost regulator as current-mode controller with two control loops, which work together in maintaining a constant output voltage and supply the required load current. The inner current control loop provides cycle-by-cycle current limiting, while the output control loop provides output voltage control. When the boost converter is turned on using the DIN input, the NMOS switch is turned on and the inductor current ramps up to its peak value, approximately 1600mA nominally.

The current comparator turns off the NMOS switch for a fixed period of time to allow energy to be transferred to the output capacitor. When the voltage on the output capacitor equals or exceeds the desired output voltage, the current loop is disabled until the load discharges the output capacitor to a voltage lower than the desired output voltage. Every time the output voltage falls below the desired value, the switching cycle starts and continues until the desired value is reached. The constant switching resulting in the charging and discharging of the output capacitor causes a ripple on the output voltage. The ripple on the output voltage depends on the external component parameters, such as the value of external capacitor, its ESR, and etc.

In PAM8907, when logic high is asserted on the DIN pin, the boost regulator is enabled. However, the Piezo driver output is not enabled until the output voltage reaches its nominal set point (total soft-start time around 1.1ms). This ensures the output voltage rises quickly to the necessary drive voltage for the Piezo.

The boost regulator has been optimized to work with the external components as shown in the Typical Application circuit. It is crucial to select an appropriate inductor value for the boost converter to operate efficiently with expected transient behavior and loop stability under a limited board space condition. 0.68µH to 1.5µH (typical 1.0µH) inductor with saturation current rating of 1A is recommended to optimize PAM8907 performance.



### Application Information (continued)

#### Capacitor Selection Guide

The external capacitors are required to use low ESR ceramic capacitors. It is highly recommended to place them at the same layout layer as PAM8907.

#### • Power Supply Decoupling – VIN (Pin 10)

Capacitor Value: 1µF +10µF

Voltage Rating: 2 x VIN

Capacitor layout: place the 1µF capacitor close to VIN (Pin 10), and 10µF close to the inductor

If the application uses the battery like CR2032 which cannot support higher current, it is highly recommended to change  $10\mu$ F to  $47\mu$ F or above.

#### • External LDO – VCC (Pin 1)

Capacitor Value: 1μF Voltage Rating: 10V or 16V Capacitor layout: place the capacitor close to VCC (Pin 1) If the application uses the battery like CR2032 which cannot support higher current, it is highly recommended to change 1μF to 0.47μF.

#### • Bootstrap – BOOT (Pin 3)

Capacitor Value: 0.1µF Voltage Rating: 25V or higher Capacitor layout: place the capacitor close to BOOT (Pin 3)

#### • Boost Output – VOUT (Pin 5)

Capacitor Value: 1µF or 2.2µF, for smoke alarm application, if loading is higher than 100nF, put a 10µF capacitor at the V<sub>OUT</sub> pin. Voltage Rating: 25V or higher

Capacitor layout: place the capacitor close to VOUT (Pin 5)

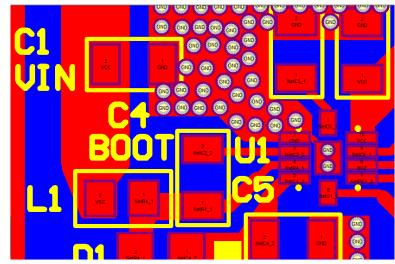
If the application uses the battery like CR2032 which cannot support higher current, it is highly recommended to change the 1µF to 0.47µF.

#### **Schottky Diode**

This is optional. A Schottky diode between SW and VOUT (in parallel with high-side FET of the boost converter) can reduce the power consumption by approximately 20%. A 20V Schottky with current rating of 1A is preferred.

#### **GND Layout Guideline**

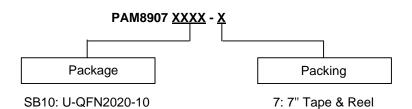
The GND layout is important to enable PAM8907 to operate under optimal conditions. Suggested layout for GND is illustrated below. Please consult with Diodes Incorporated's technical support team or field representative for any further assistance, if necessary.



Connect first GND (Pin 2) to PAM8907's epoxy pad, expand the GND line to VCC/VIN's capacitor's GND and place many vias on the GND trace, then connect with VOUT pin's CAP GND. Place these capacitors as close as possible to PAM8907.



## **Ordering Information**



Part Number	Paakaga	Voltago	Packing	
	Package	Voltage	Qty.	Carrier
PAM8907SB10-7	U-QFN2020-10	11V/15.6V	3,000	Tape & Reel

## **Marking Information**

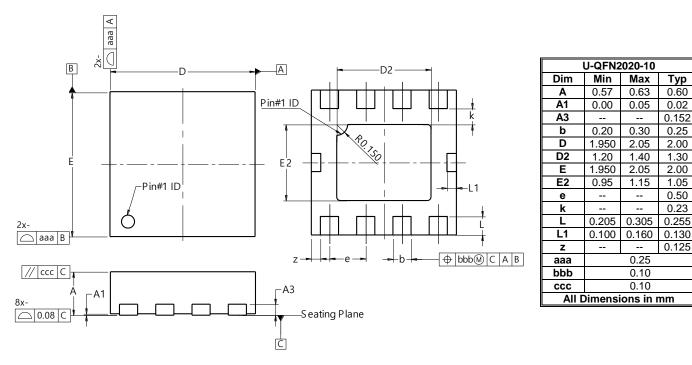
( Top View )	
	XX : Identification Code
XX	<u>Y</u> : Year : 0 to 9
<u>////</u>	<u>W</u> : Week : A to Z : 1 to 26 Week;
<u>Y W X</u>	a to z : 27 to 52 Week; z Represents
•	52 and 53 Week
	<u>X</u> : Internal Code

Part Number	Package	Identification Code
PAM8907SB10-7	U-QFN2020-10	PJ



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

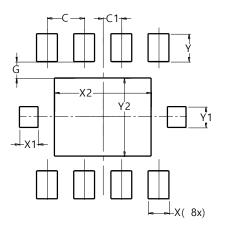


## U-QFN2020-10

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-QFN2020-10



Dimensions	Value (in mm)
С	0.500
C1	0.250
G	0.220
Х	0.280
X1	0.250
X2	1.300
Y	0.375
Y1	0.280
Y2	1.050

### **Mechanical Data**

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per J-STD-002, Test B1 (4)
- Weight: 13.67mg (Approximate)



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